2SA0794 (2SA794), **2SA0794A** (2SA794A)

Silicon PNP epitaxial planar type

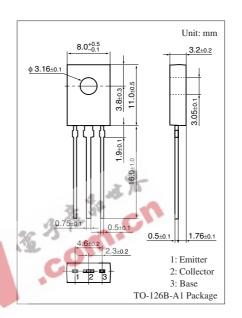
For low-frequency output driver Complementary to 2SC1567, 2SC1567A

■ Features

- \bullet High collector-emitter voltage (Base open) V_{CEO}
- Optimum for the driver stage of low-frequency and 40 W to 100 W output amplifier
- TO-126B package which requires no insulation plate for installation to the heat sink

■ Absolute Maximum Ratings $T_a = 25$ °C

| Parameter | Symbol | Rating | Unit | |
|-----------------------------|----------------|-------------|------|-------|
| Collector-base voltage | 2SA0794 | V_{CBO} | -100 | V |
| (Emitter open) | 2SA0794A | | -120 | |
| Collector-emitter voltage | 2SA0794 | V_{CEO} | -100 | V |
| (Base open) | 2SA0794A | | -120 | ١٠)١١ |
| Emitter-base voltage (Coll | V_{EBO} | -5 | V | |
| Collector current | I_{C} | - 0.5 | A | |
| Peak collector current | I_{CP} | -1 | A | |
| Collector power dissipation | P _C | 1.2 | W | |
| Junction temperature | T_{j} | 150 | °C | |
| Storage temperature | T_{stg} | -55 to +150 | °C | |



■ Electrical Characteristics $T_a = 25$ °C ± 3 °C

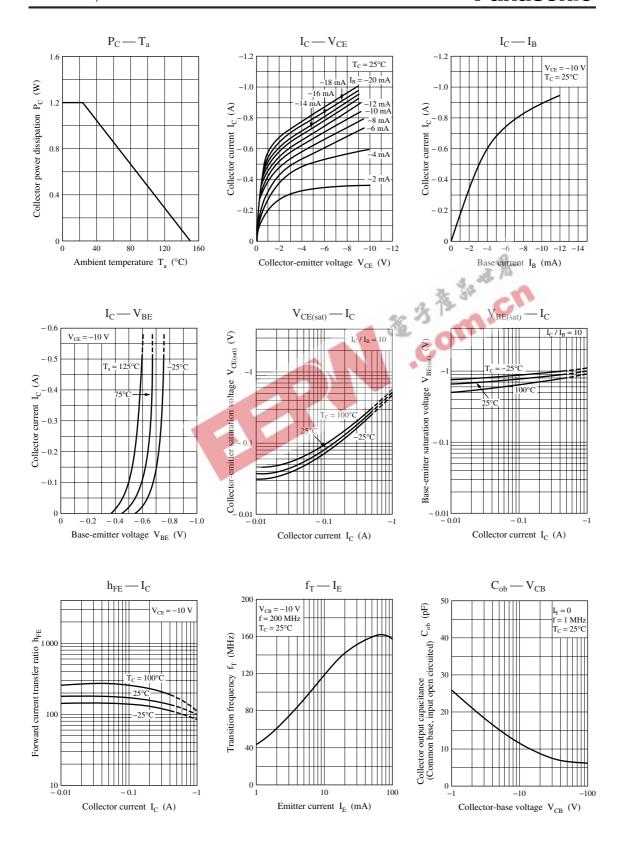
| Parameter | | Symbol | Conditions | Min | Тур | Max | Unit |
|------------------------------|------------|----------------------|--|------|--------|-------|------|
| Collector-emitter voltage | 2SA0794 | V _{CEO} | $I_C = -100 \ \mu A, I_B = 0$ | -100 | | | V |
| (Base open) | 2SA0794A | | | -120 | | | |
| Emitter-base voltage (Colle | ctor open) | V _{EBO} | $I_E = -1 \mu A, I_C = 0$ | -5 | | | V |
| Forward current transfer rat | io | h _{FE1} * | $V_{CE} = -10 \text{ V}, I_{C} = -150 \text{ mA}$ | 90 | | 220 | _ |
| | | h _{FE2} | $V_{CE} = -5 \text{ V}, I_{C} = -500 \text{ mA}$ | 50 | 100 | | |
| Collector-emitter saturation | voltage | V _{CE(sat)} | $I_C = -500 \text{ mA}, I_B = -50 \text{ mA}$ | | - 0.2 | - 0.4 | V |
| Base-emitter saturation volt | age | V _{BE(sat)} | $I_C = -500 \text{ mA}, I_B = -50 \text{ mA}$ | | - 0.85 | -1.20 | V |
| Transition frequency | | f_T | $V_{CB} = -10 \text{ V}, I_E = 50 \text{ mA}, f = 200 \text{ MHz}$ | | 120 | | MHz |
| Collector output capacitance | e | C _{ob} | $V_{CB} = -10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$ | | 20 | 30 | pF |
| (Common base, input open | circuited) | | | | | | |

 $Note) \ 1. \ Measuring \ methods \ are \ based \ on \ JAPANESE \ INDUSTRIAL \ STANDARD \ JIS \ C \ 7030 \ measuring \ methods \ for \ transistors.$

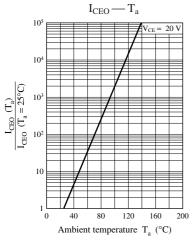
2. *: Rank classification

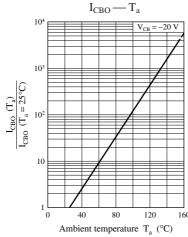
| Rank | Q | R |
|------------------|-----------|------------|
| h _{FE1} | 90 to 155 | 130 to 220 |

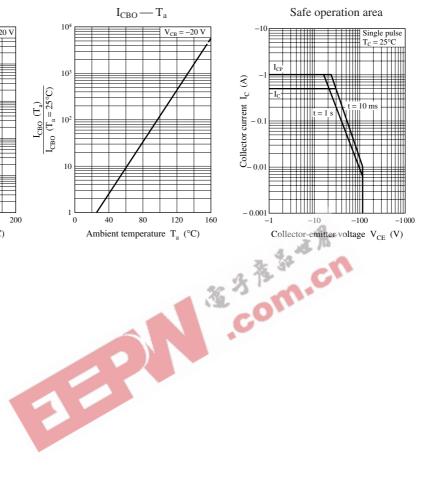
Note) The part numbers in the parenthesis show conventional part number.



2 SJD00001BED









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